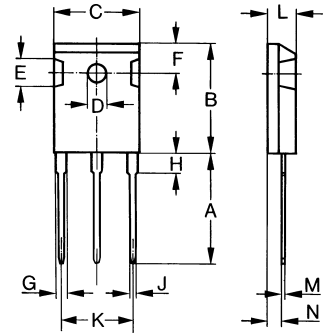
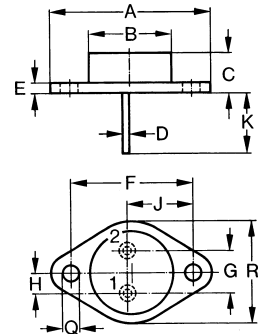


Symbol	Test Conditions	Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified)		
		min.	typ.	max.
g_{fs}	$V_{DS} = 10\text{ V}; I_D = 0.5 \cdot I_{D25}$, pulse test	11	18	S
C_{iss}	$V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$		4500	pF
C_{oss}			420	pF
C_{rss}			140	pF
$t_{d(on)}$	$V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$ $R_G = 2\ \Omega$ (External)		20	40 ns
t_r			43	60 ns
$t_{d(off)}$			70	90 ns
t_f			40	60 ns
$Q_{g(on)}$	$V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$		151	170 nC
Q_{gs}			29	40 nC
Q_{gd}			60	85 nC
R_{thJC}			0.25	0.42 K/W
R_{thCK}				K/W

Source-Drain Diode		Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified)		
Symbol	Test Conditions	min.	typ.	max.
I_S	$V_{GS} = 0\text{ V}$	15N60 20N60		15 A 20 A
I_{SM}	Repetitive; pulse width limited by T_{JM}	15N60 20N60		60 A 80 A
V_{SD}	$I_F = I_S, V_{GS} = 0\text{ V}$, Pulse test, $t \leq 300\ \mu\text{s}$, duty cycle $d \leq 2\%$			1.5 V
t_{rr}	$I_F = I_S$ $-di/dt = 100\text{ A}/\mu\text{s}$, $V_R = 100\text{ V}$	$T_J = 25^\circ\text{C}$		250 ns
		$T_J = 125^\circ\text{C}$		400 ns
Q_{RM}		$T_J = 25^\circ\text{C}$		1 μC
		$T_J = 125^\circ\text{C}$		2 μC
I_{RM}		$T_J = 25^\circ\text{C}$		10 A
		$T_J = 125^\circ\text{C}$		15 A

TO-247 AD (IXFH) Outline


Dim.	Millimeter Min. Max.	Inches Min. Max.
A	19.81 20.32	0.780 0.800
B	20.80 21.46	0.819 0.845
C	15.75 16.26	0.610 0.640
D	3.55 3.65	0.140 0.144
E	4.32 5.49	0.170 0.216
F	5.4 6.2	0.212 0.244
G	1.65 2.13	0.065 0.084
H	- 4.5	- 0.177
J	1.0 1.4	0.040 0.055
K	10.8 11.0	0.426 0.433
L	4.7 5.3	0.185 0.209
M	0.4 0.8	0.016 0.031
N	1.5 2.49	0.087 0.102

TO-204 AE (IXFM) Outline


Dim.	Millimeter Min. Max.	Inches Min. Max.
A	38.61 39.12	1.520 1.540
B	- 22.22	- 0.875
C	6.40 11.40	0.252 0.449
D	1.45 1.60	0.057 0.063
E	1.52 3.43	0.060 0.135
F	30.15 BSC	1.187 BSC
G	10.67 11.17	0.420 0.440
H	5.21 5.71	0.205 0.225
J	16.64 17.14	0.655 0.675
K	11.18 12.19	0.440 0.480
Q	3.84 4.19	0.151 0.165
R	25.16 26.66	0.991 1.050

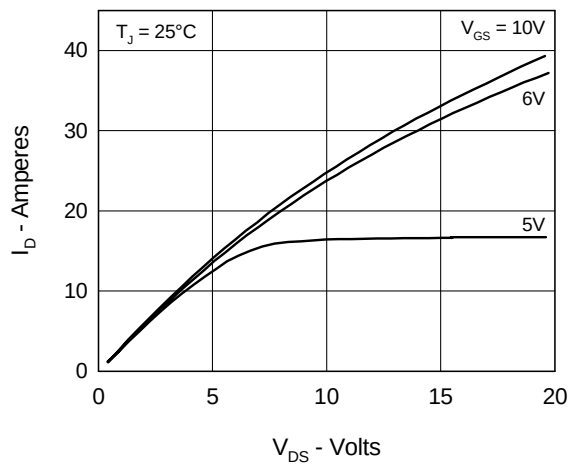
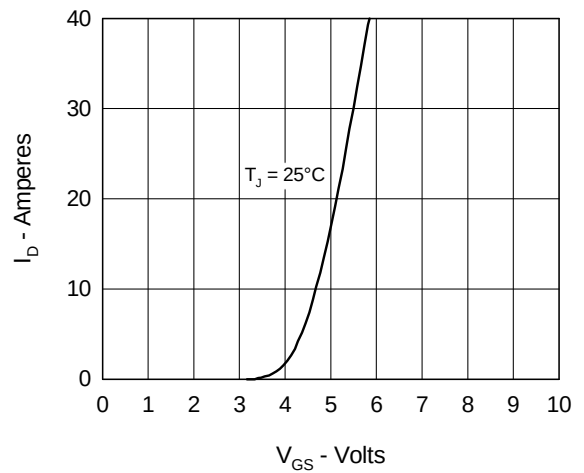
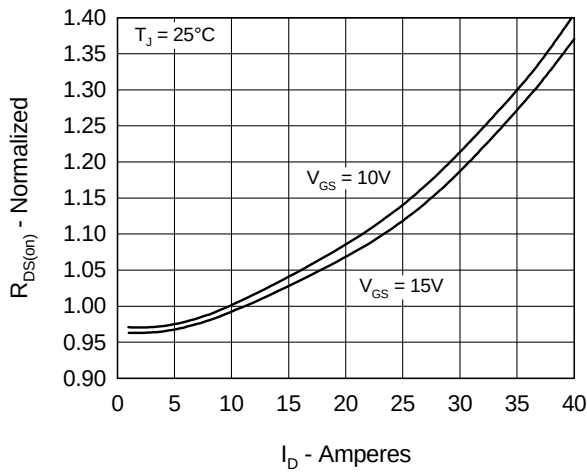
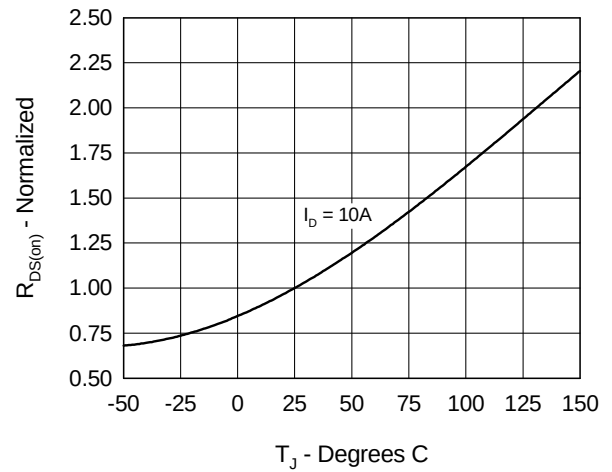
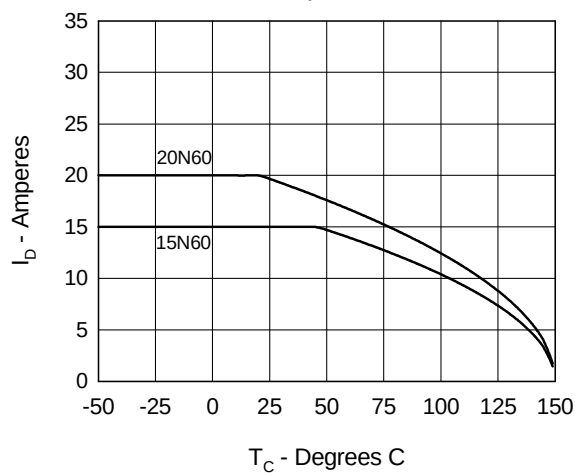
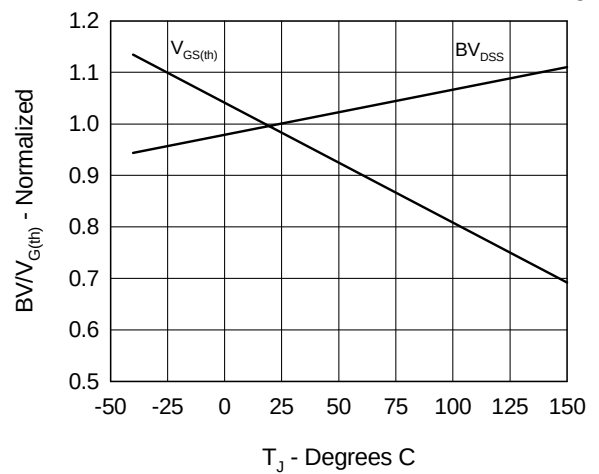
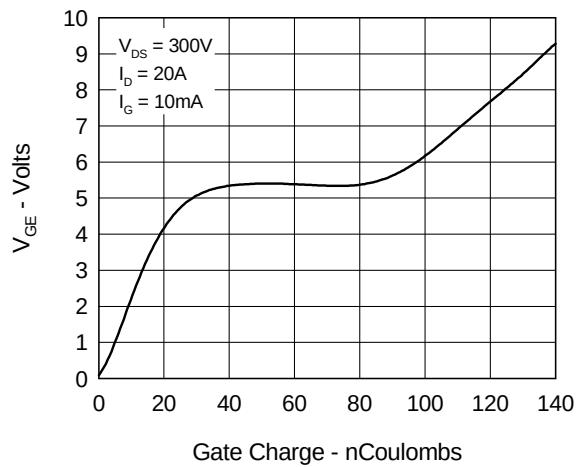
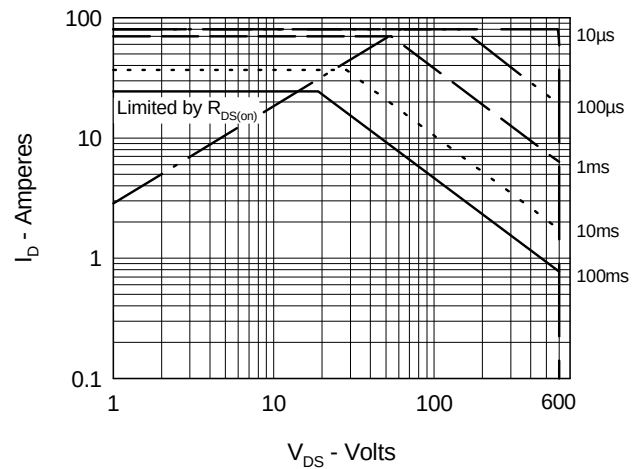
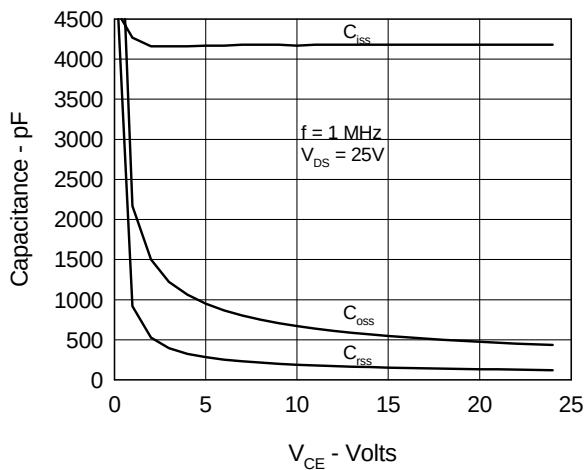
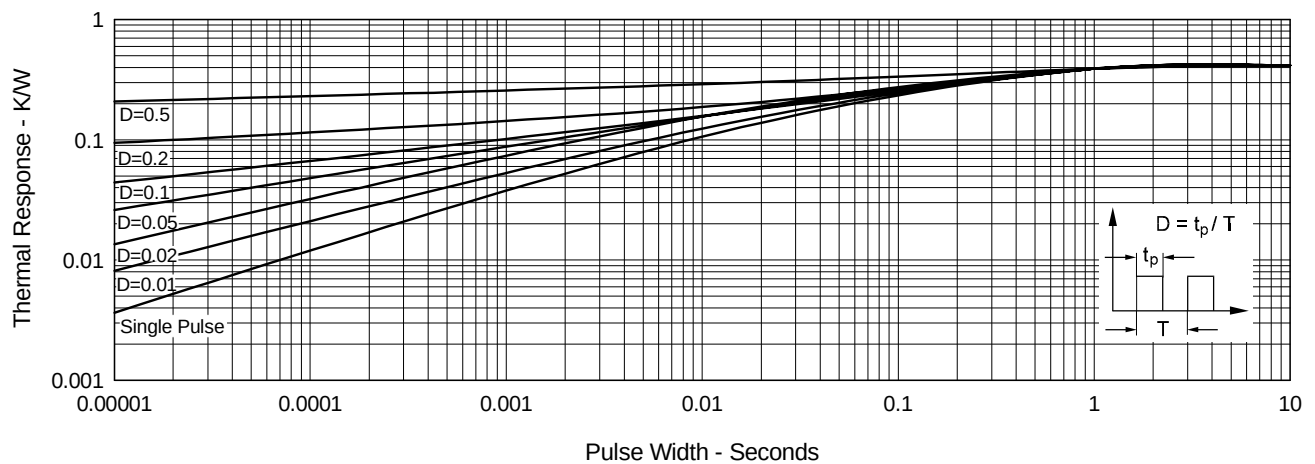
Fig. 1 Output Characteristics

Fig. 2 Input Admittance

Fig. 3 $R_{DS(on)}$ vs. Drain Current

Fig. 4 Temperature Dependence of Drain to Source Resistance

Fig. 5 Drain Current vs. Case Temperature

Fig. 6 Temperature Dependence of Breakdown and Threshold Voltage


Fig.7 Gate Charge Characteristic Curve

Fig.8 Forward Bias Safe Operating Area

Fig.9 Capacitance Curves

Fig.10 Transient Thermal Impedance




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